



Elettra Sincrotrone Trieste

The **ESS** WS OFE

Sandi Grulja

Themes:

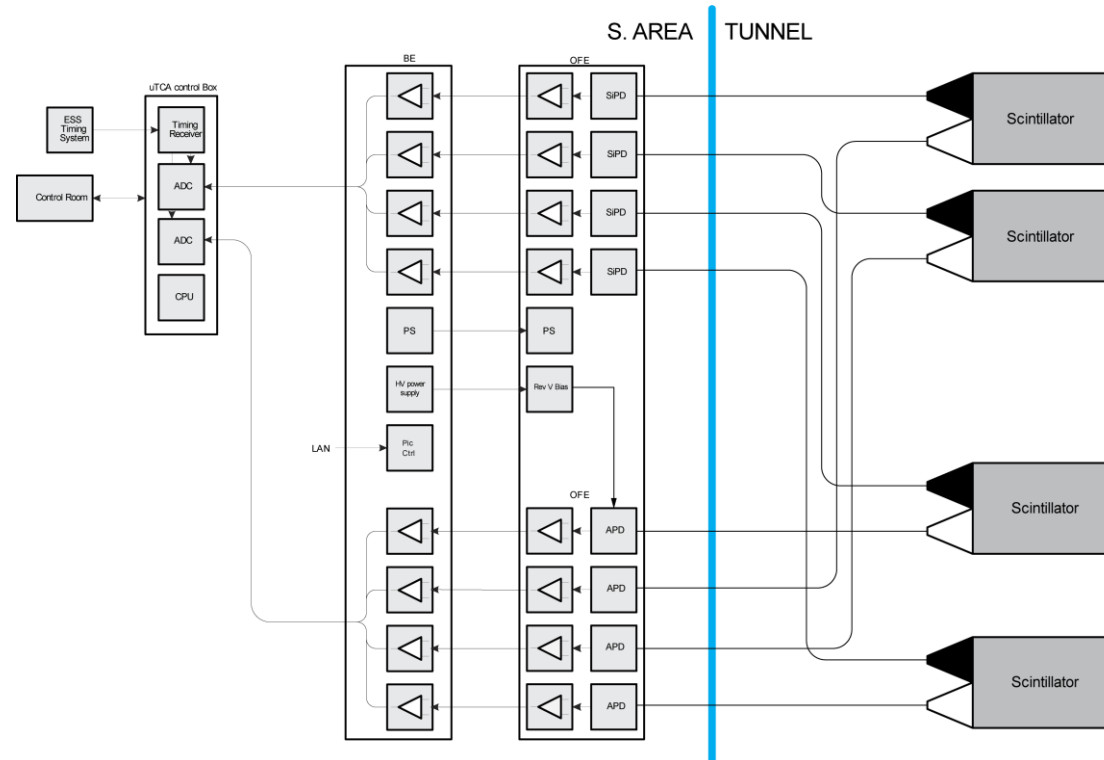
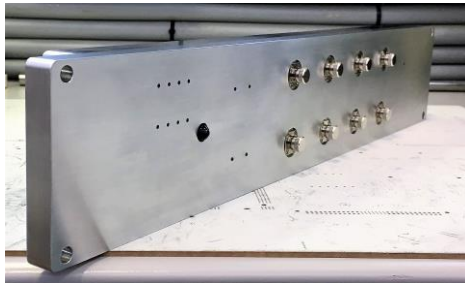
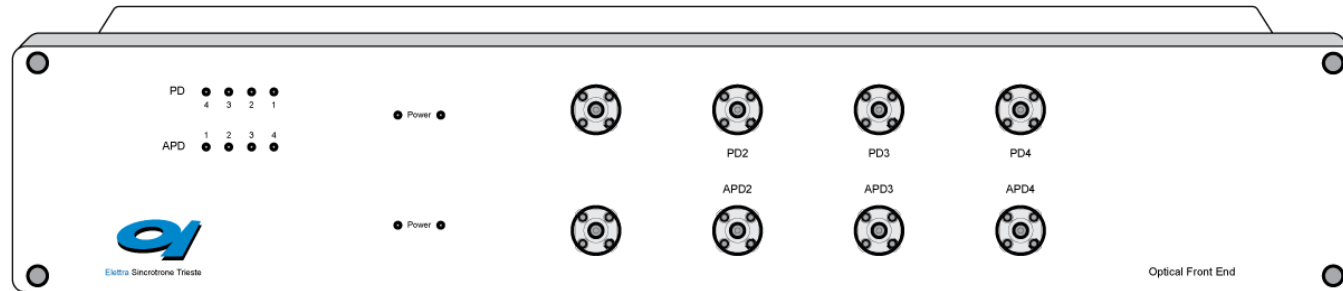
- OFE Component specifications and schematic design
- OFE electrical tests
- OFE Hardware and assembly
- OFE Mechanical design



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Optical Front End

Block schematics



General Technical specifications

OFE tech specifications:

- low-voltage noise JFET-input stage
- Power supply -5V to +5V
- High Gain Bandwidth Product 1.6 GHz
- High Bandwidth 275 MHz
- Slew Rate 700 V/ μ s
- Operating Temperature Range -40°C to 85°C
- Low-Input Offset Voltage ± 250 μ V
- Low-Input Bias Current 2 pA
- Low-Input Voltage Noise 4.8 nV/ $\sqrt{\text{Hz}}$
- Input noise current 1.8 pA/ $\sqrt{\text{Hz}}$
- High-Output Current 70 mA
- Output voltage range 0 to - 4.5 V
- Optical power sensitivity 1nW
- Optical power range 1nW – 60uW

Si Photo Diode (PD) Hamamatsu S1226-44BQ

- Photo sensitivity area 3.6 x 3.6 mm
- Operating temperature -20 to +60 deg. C
- Spectral response range 190 to 1000 nm
- Peak sensitivity wavelength 720 nm
- Photosensitivity 0.36 A/W
- Dark current 10 pA
- Terminal capacitance 500 pF

Avalanche Si Photo diode (APD) Hamamatsu S5544

- Photo sensitivity area fi 3.0 mm
- Operating temperature -20 to +60 deg. C
- Spectral response range 200 to 1000 nm
- Peak sensitivity wavelength 620 nm
- Photosensitivity 0.42 A/W
- Dark current Typ 1 nA max 30 nA
- Terminal capacitance 120 pF
- Break down voltage typ 150V max 200V

Power Supply

- Main power supply (BE) -5V / +5V
- Main current max -100 mA / +200 mA
- Bias High Voltage (BE) 0 V to max +200V
must be software limited to +150V
- Internal Bias High Voltage 0 V to max +200V

Mechanical specifications

- Aluminum milled unibody case
- Mechanical dimension 19 inch 1U rack mount case
W-483mm H-88mm D-50mm
- Weight 1934.35 g

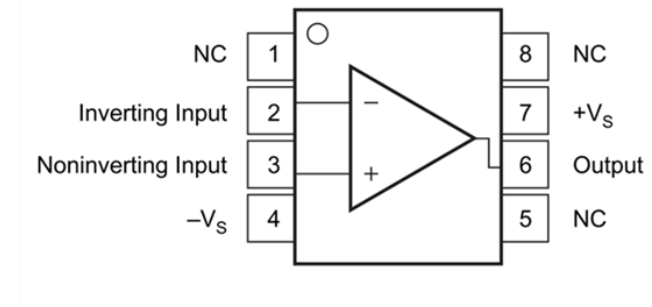
OPA657 1.6-GHz, Low-Noise, FET-Input Trans Impedance Amplifier

Features:

- High Gain Bandwidth Product: 1.6 GHz
- High Bandwidth: 275 MHz
- Slew Rate: 700 V/ μ s
- Operating Temperature Range: -40° C to 85° C
- Low-Input Offset Voltage: ± 250 μ V
- Low-Input Bias Current: 2 pA
- Low-Input Voltage Noise: 4.8 nV/ $\sqrt{\text{Hz}}$
- Low input noise current of: 1.8 pA/ $\sqrt{\text{Hz}}$
- High-Output Current: 70 mA

Supply voltage:

± 5 V DC



SiPD - HAM S1226-44BQ Characteristics:

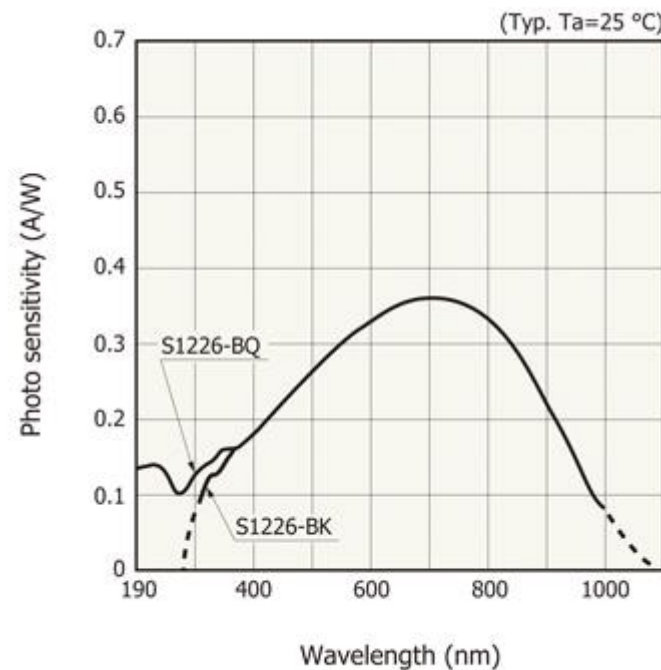
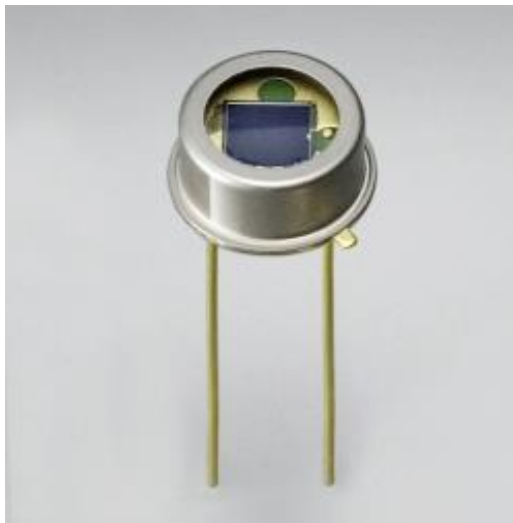
- Active Area of photo diode 3.6 x 3.6 mm
- Reverse bias voltage 5V
- Wave length 190 to 1000nm peak 720nm
- Photo sensitivity - 0.36A/W
- Dark current I_d 10pA
- Cd 500pF

$$Responsivity_{PhD} = \frac{I_d}{W}$$

$$Area = a^2 (cm^2)$$

$$O_p = \frac{W}{Area}$$

SiPD I_d 5uA = 107.25uW of optical power



SiAPD - HAM S5344 Characteristics:

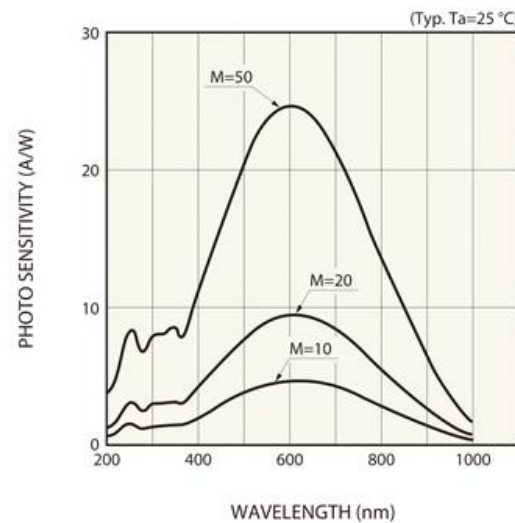
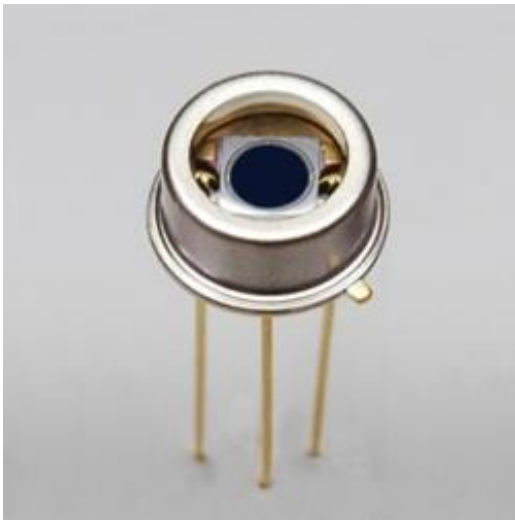
- Active Area of photo diode ϕ 3mm
- Breakdown voltage 150V I_d 100uA
- Wave length 200 to 1000nm peak 620nm
- Photo sensitivity - 0.42A/W
- Dark current I_d 1nA
- Cd 120pF

$$\text{Responsivity}_{PhD} = \frac{I_d}{W}$$

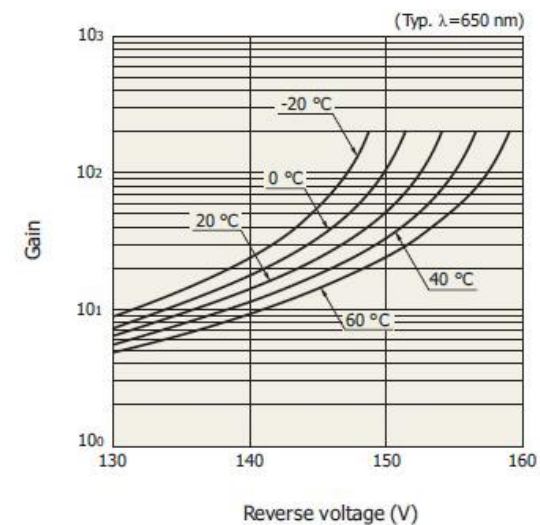
$$\text{Area} = \pi r^2 (\text{cm}^2)$$

$$O_p = \frac{W}{\text{Area}}$$

SiAPD I_d 5uA = 168.36uW of optical power



KAPDB0010ED



KAPDB0011EC



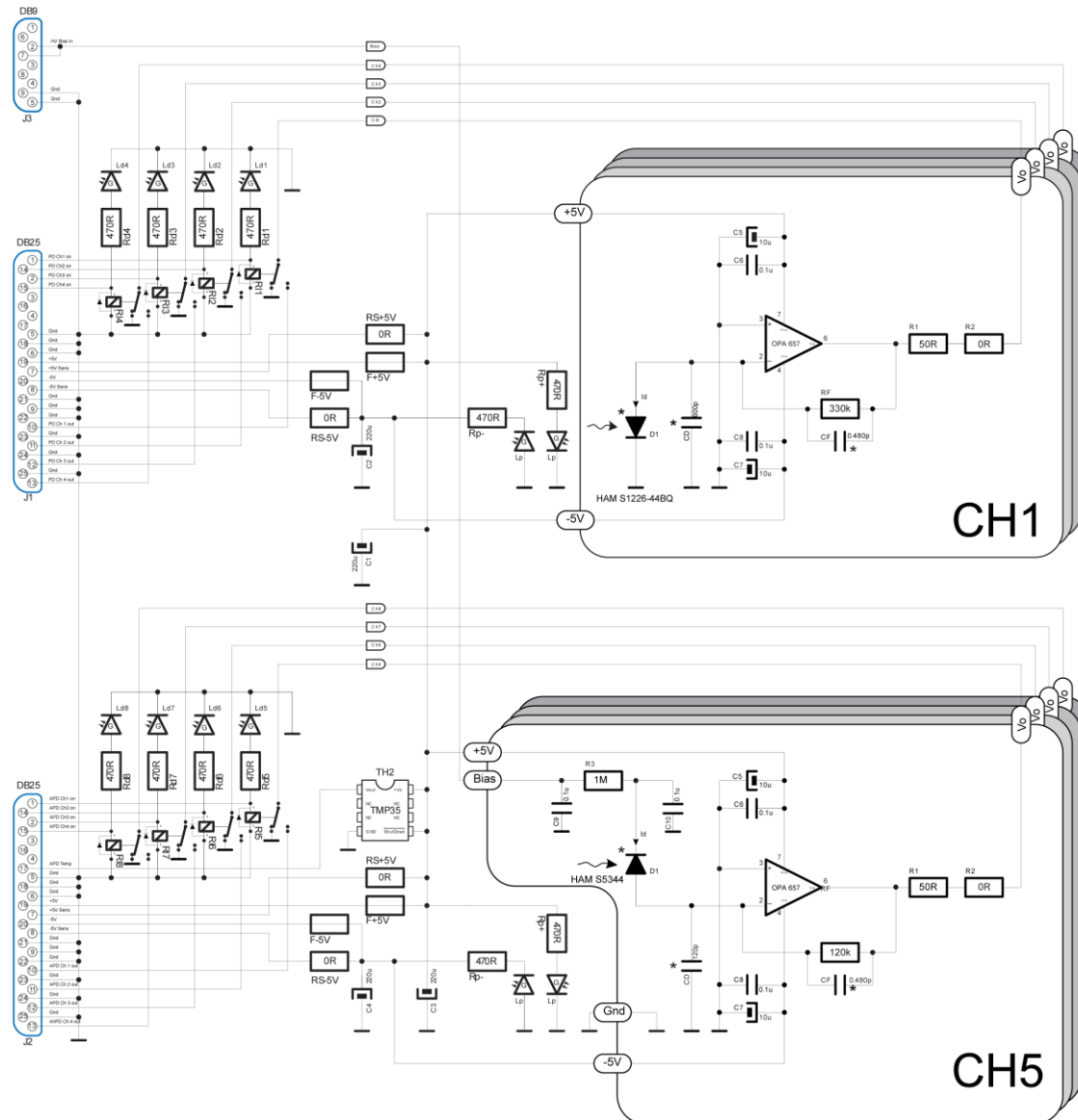
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Electrical schematic

- Single pcb design
- Temperature sensor
- Input selector with led indicators
- Power supply led indicators
- Channel selector



4 ch Si PD amp

4 ch Si APD amp

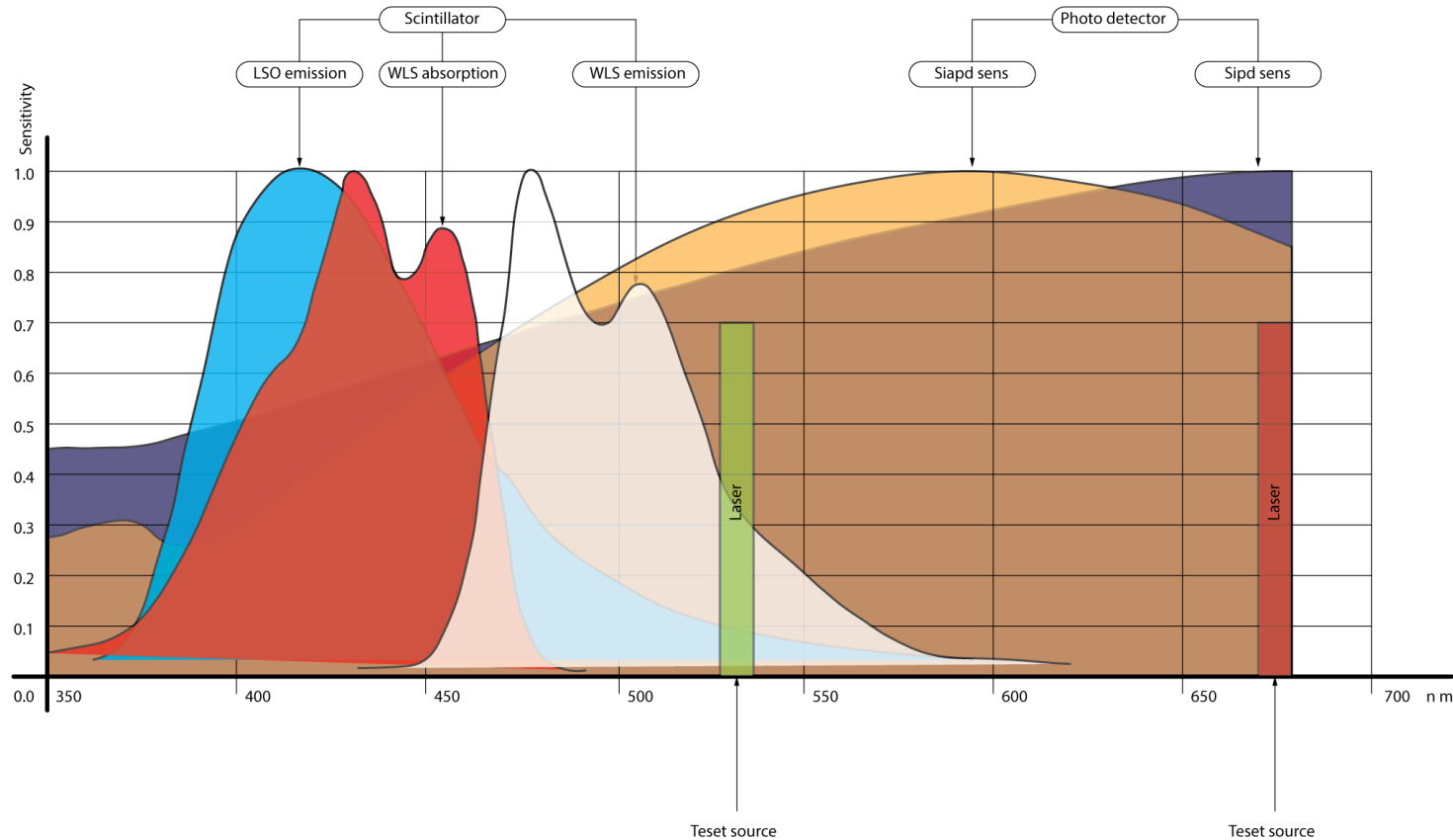


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Optical Front End



Opto - Electrical test



The light wave length specter expected from scintillator to optical fiber transported to silicon photo detectors



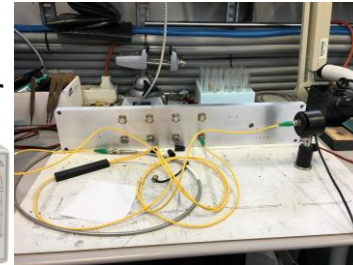
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Optical Front End light measurement



Keithley multimeter

With SiPD 1nW light
power easily measured



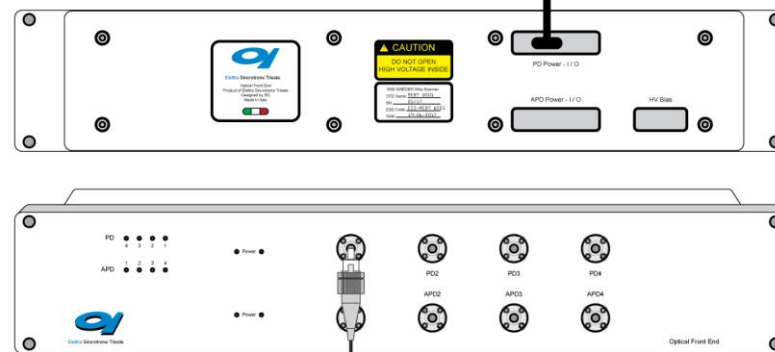
SiPD output



Image of the measured light power



Thorlabs power meter



Optical fiber

Polarizer for light power regulation

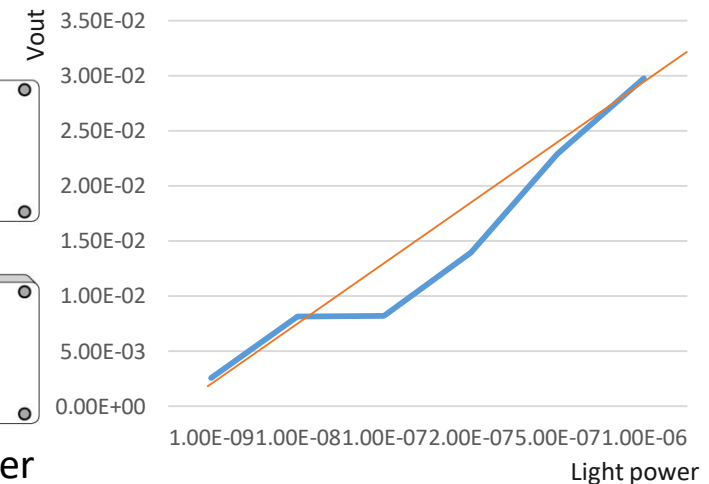
Fiber splitter



Thorlabs 5 mW - 670 nm laser

Light power from 1nW to 60 uW

PC Thorlabs software
for power meter



Assembled OFE electronics in Aluminum milled body

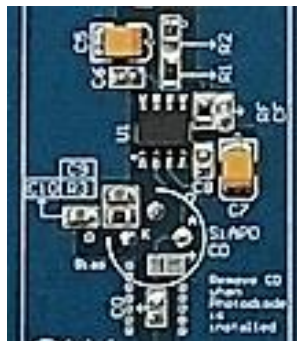
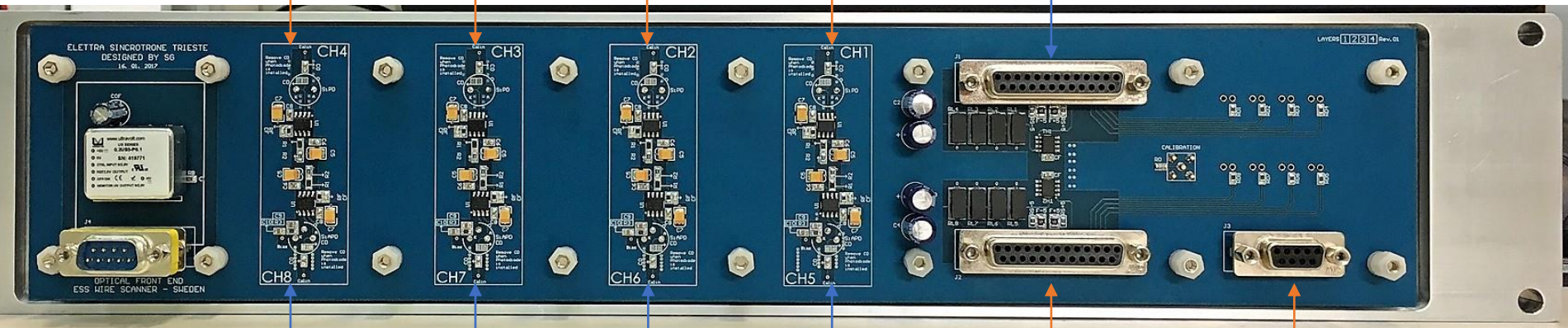
SiPD amplifier

Back End controlled PS, CH selector, and Signal Output

SiAPD amplifier

Back End controlled PS, HV biasing, CH selector, Signal Output and Temp measurement

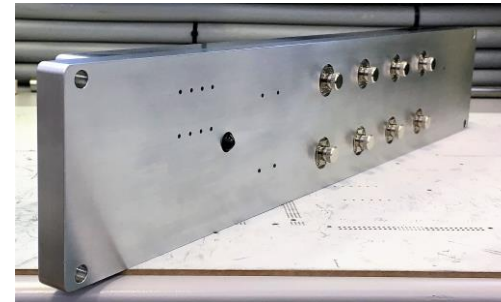
Assembled detail





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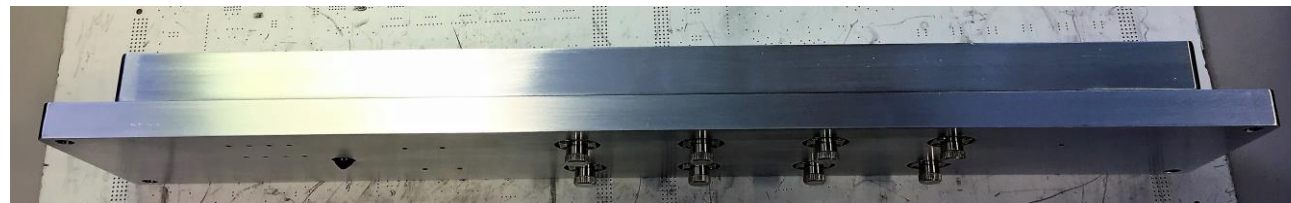
Optical Front End



Aluminum
milled body



Connections
on the back

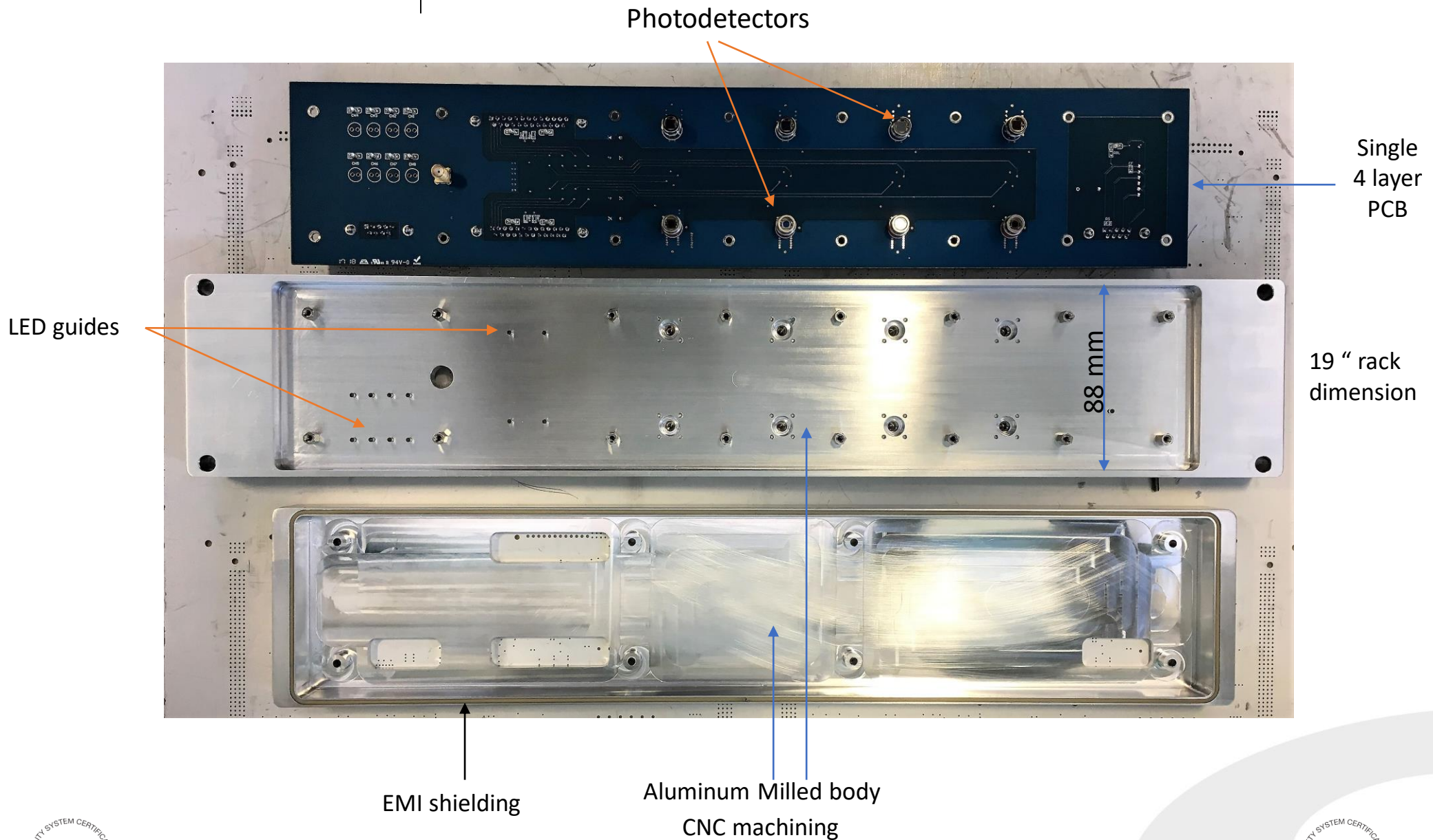


Slim and
compact design



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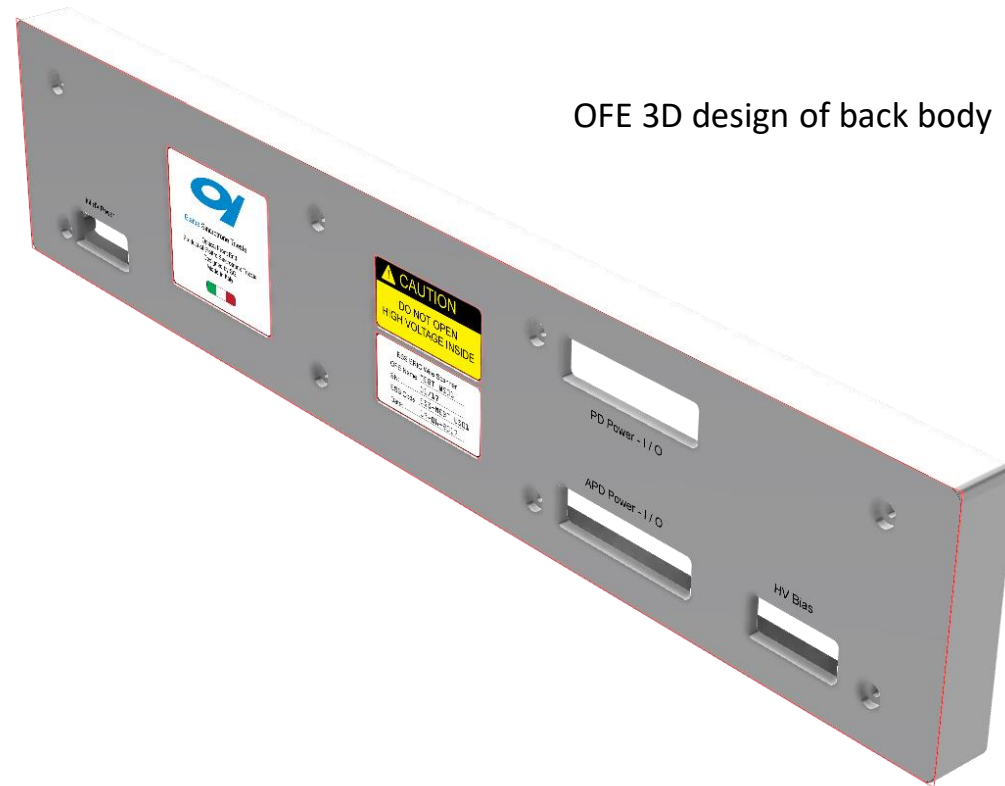
Optical Front End hardware





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Optical Front End Mechanical design

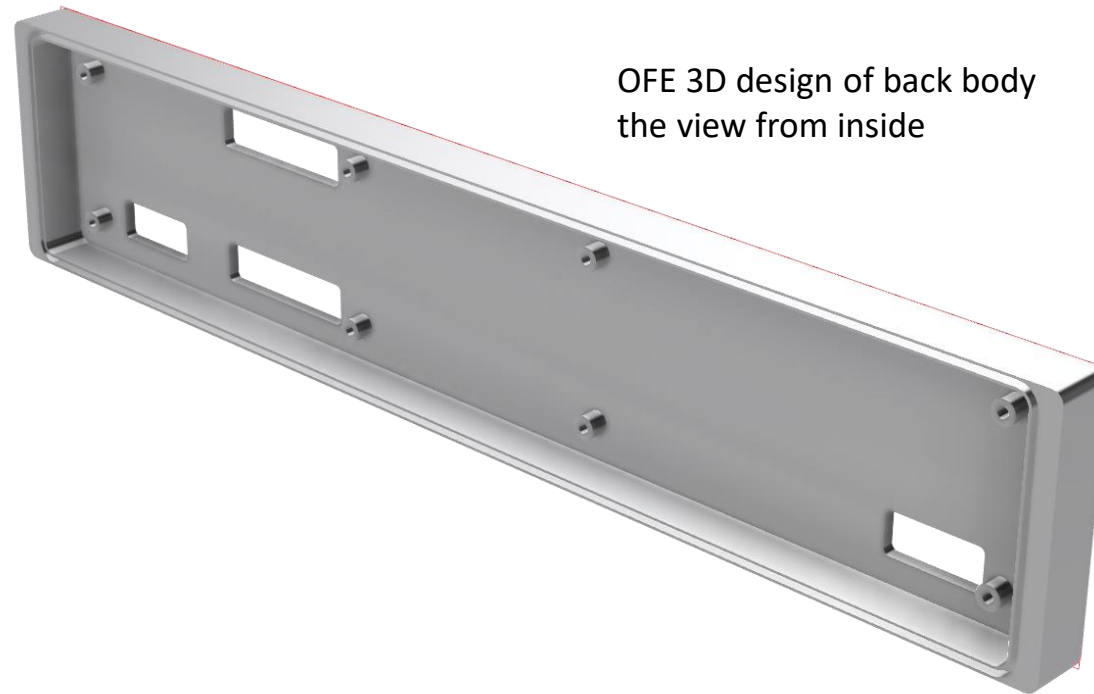


OFE 3D design of back body



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Optical Front End Mechanical design



OFE 3D design of back body
the view from inside

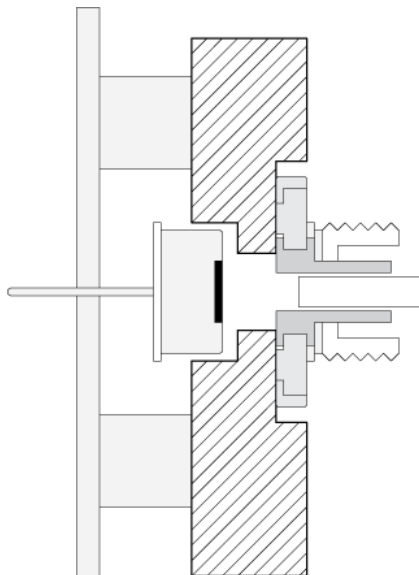
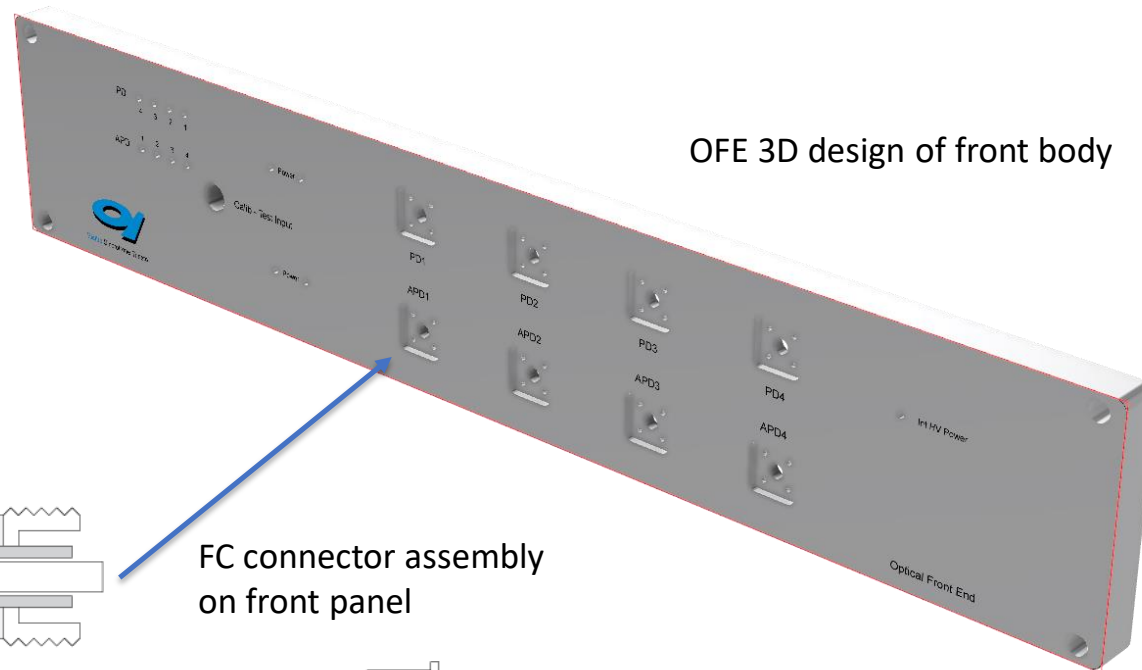


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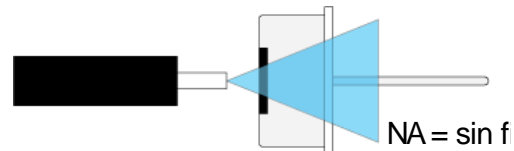
Optical Front End Mechanical design



OFE 3D design of front body



FC connector assembly
on front panel

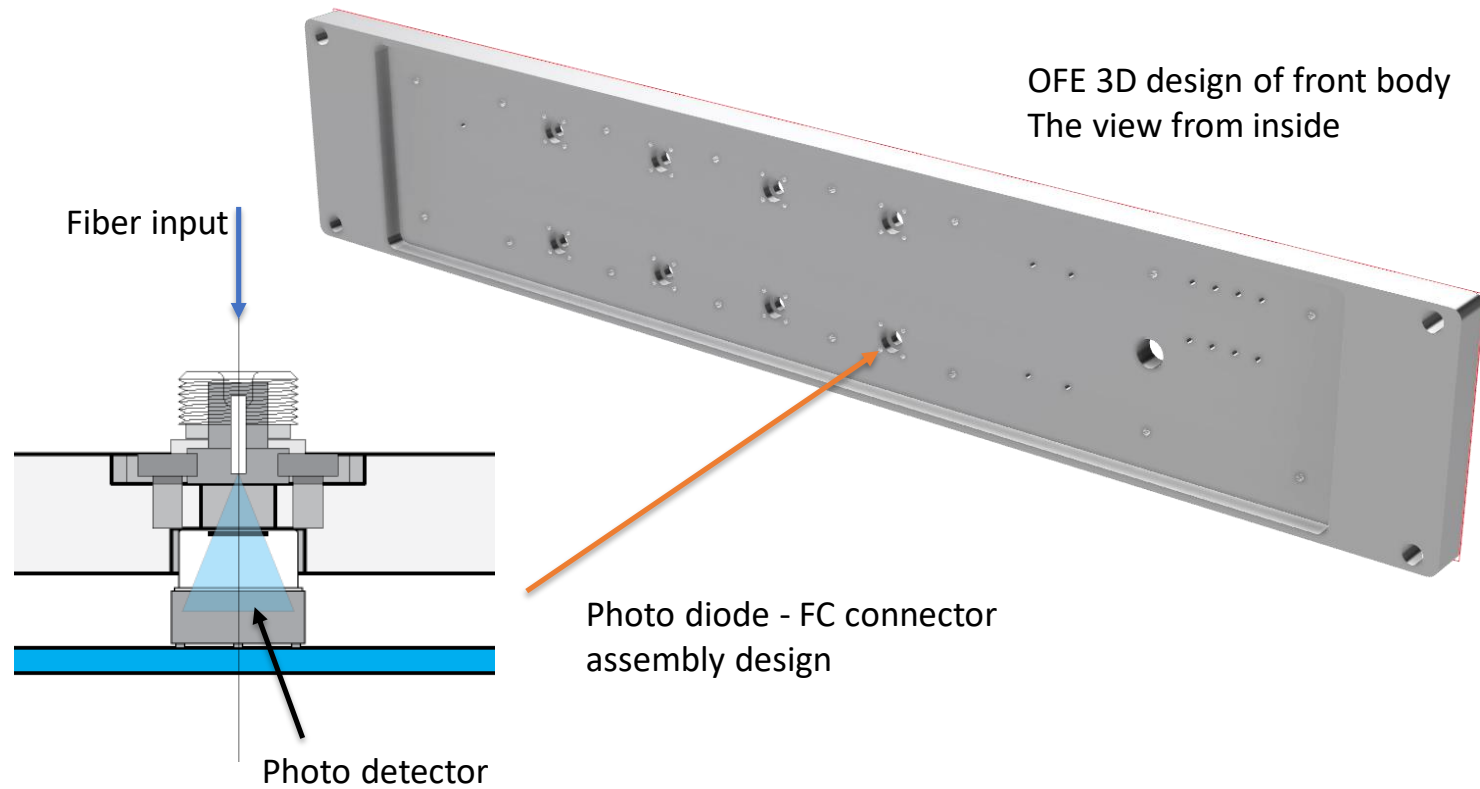


Numerical Aperture of Optical Fiber



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Thank you !